

CLAIMS:

1. An electro-optical device having an ITO (indium tin oxide) layer and a SiN layer near the ITO layer, characterized in that an intermediate layer of silicon oxide is provided between the ITO layer and the SiN layer.

2. An electro-optical device as claimed in claim 1, characterized in that the electro-optical device is a fingerprint sensor.

3. An electro-optical device as claimed in claim 1, characterized in that the electro-optical device is an X-ray image sensor.

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